

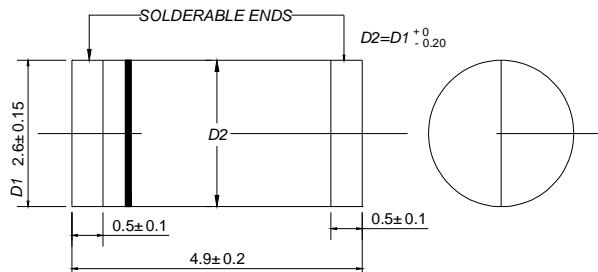


DL5817 THRU DL5819

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 20 --- 40 VCURRENT: 1.0 A

DO-213AB



Dimensions in millimeters

FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-213AB, molded plastic
- ◇ Terminals: Solderable per MIL-STD-202, method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.0046 ounces, 0.116 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

MDD Catalog Number		DL5817	DL5818	DL5819	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	V
Maximum RMS voltage	V_{RMS}	14	21	28	V
Maximum DC blocking voltage	V_{DC}	20	30	40	V
Maximum average forward rectified current @ $T_A = 90^\circ\text{C}$	$I_{F(AV)}$		1.0		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}		25		A
Maximum instantaneous forward voltage @ 1.0A (Note 1) @ 3.0A	V_F	0.45 0.75	0.55 0.875	0.60 0.90	V
Maximum reverse current @ $T_A = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_A = 100^\circ\text{C}$	I_R		1.0 10.0		mA
Typical junction capacitance (Note 2)	C_J		110		pF
Typical thermal resistance (Note 3)	$R_{\theta JA}$		80		°C/W
Operating junction temperature range	T_J		- 55 ---- + 150		°C
Storage temperature range	T_{STG}		- 55 ---- + 150		°C

NOTE: 1. Pulse test : 300 μs pulse width, 1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient, vertical PC board mounting, 0.5"(12.7mm) lead length.

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RATINGS AND CHARACTERISTIC CURVES DL5817 THRU DL5819

FIG.1 – FORWARD DERATING CURVE

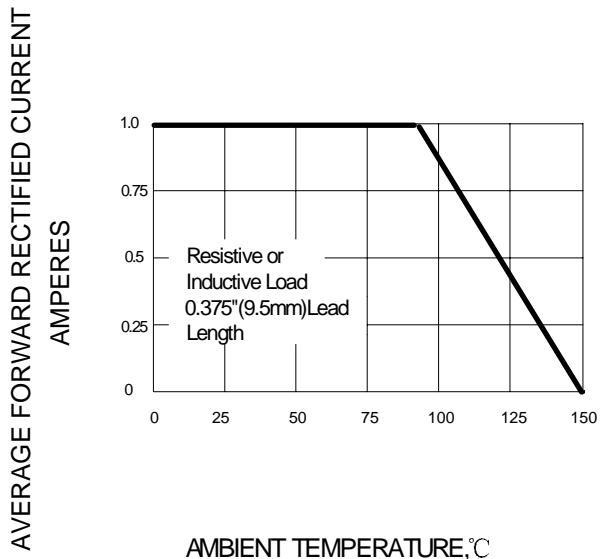


FIG.2 – PEAK FORWARD SURGE CURRENT

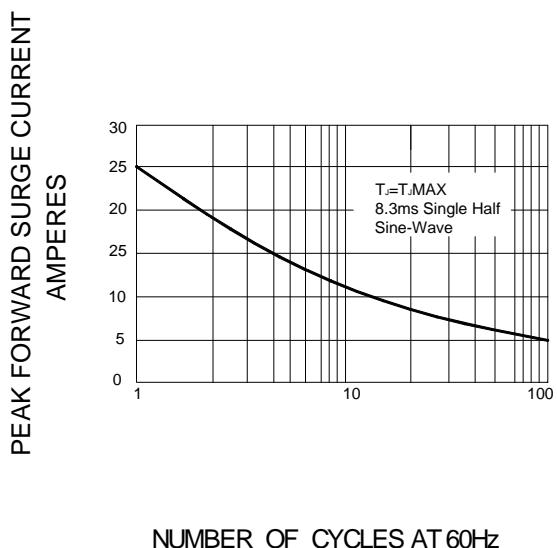


FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

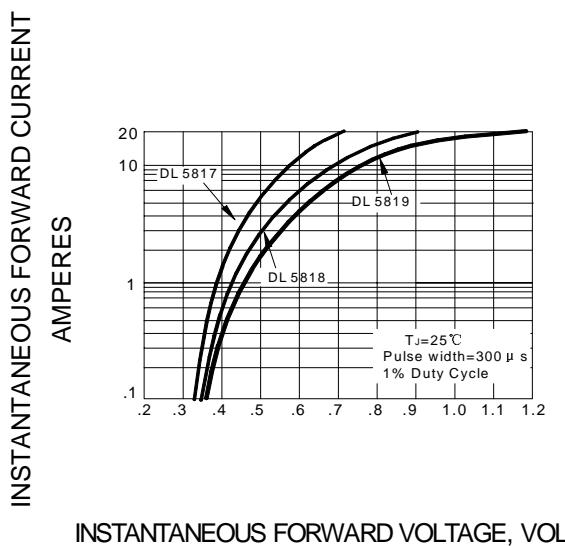
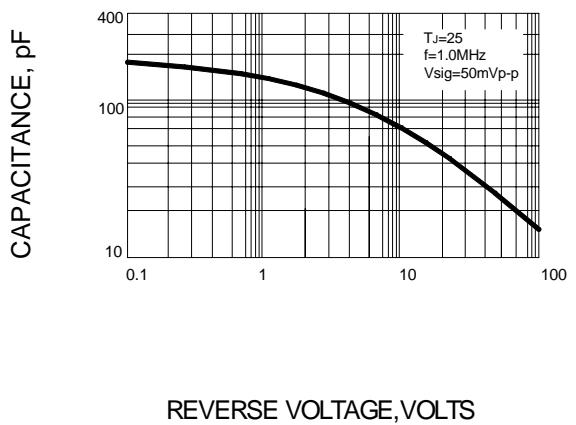


FIG.4 – TYPICAL JUNCTION CAPACITANCE



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

REVERSE VOLTAGE, VOLTS

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